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EXAMINER

POMPEY, RON EVERETT

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PAPER

Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

Office Action Summary	Application No. 10/590,901	Applicant(s) SCHWARZBAUER, HERBERT	
	Examiner RON POMPEY	Art Unit 2812	

-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --

Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) OR THIRTY (30) DAYS, WHICHEVER IS LONGER, FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

Status

- 1) ☒ Responsive to communication(s) filed on 30 November 2009.
- 2a) ☒ This action is **FINAL**. 2b) ☐ This action is non-final.
- 3) ☐ Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

Disposition of Claims

- 4) ☒ Claim(s) 27-29,32 and 34-55 is/are pending in the application.
- 4a) Of the above claim(s) _____ is/are withdrawn from consideration.
- 5) ☐ Claim(s) _____ is/are allowed.
- 6) ☒ Claim(s) 27-29,32 and 34-55 is/are rejected.
- 7) ☐ Claim(s) _____ is/are objected to.
- 8) ☐ Claim(s) _____ are subject to restriction and/or election requirement.

Application Papers

- 9) ☐ The specification is objected to by the Examiner.
- 10) ☒ The drawing(s) filed on 26 August 2006 is/are: a) ☒ accepted or b) ☐ objected to by the Examiner.
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).
- 11) ☐ The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.

Priority under 35 U.S.C. § 119

- 12) ☒ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
- a) ☒ All b) ☐ Some * c) ☐ None of:
1. ☒ Certified copies of the priority documents have been received.
2. ☐ Certified copies of the priority documents have been received in Application No. _____.
3. ☐ Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).

* See the attached detailed Office action for a list of the certified copies not received.

Attachment(s)

- | | |
|--|---|
| 1) <input checked="" type="checkbox"/> Notice of References Cited (PTO-892) | 4) <input type="checkbox"/> Interview Summary (PTO-413) |
| 2) <input type="checkbox"/> Notice of Draftsperson's Patent Drawing Review (PTO-948) | Paper No(s)/Mail Date. _____ |
| 3) <input type="checkbox"/> Information Disclosure Statement(s) (PTO/SB/08) | 5) <input type="checkbox"/> Notice of Informal Patent Application |
| Paper No(s)/Mail Date _____ | 6) <input type="checkbox"/> Other: _____ |

DETAILED ACTION

Claim Rejections - 35 USC § 102

1. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless –

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

2. Claims 27, 29, 34-35, 38, 39, 42, 46-47 and 52 rejected under 35 U.S.C. 102(b) as being anticipated by Nicholas (US 4546534).

3. **Nicholas** discloses the limitations of:

In re Claim 27: A system comprising:

an electrical component (fig. 2) provided with at least one electrical contact surface (14, fig. 2);

an electrical insulating layer (2, fig. 12/15, fig. 13), which is disposed on the component, the electrical insulating layer having an opening (16 and 17, fig. 14) to expose and surround a portion of the contact surface (14, fig. 2), wherein the insulating layer having a lateral surface that delimits the opening (14, fig. 2), the electrical insulating layer being formed from at least first (2, figs. 12/14) and second (15, figs. 13/14; layer 15 is an additional layer; See col. 5, Ins. 60-62) partial insulating layers having openings (16 and 17, fig. 14) with different widths such that a stepped structure is formed from the contact surface to the first partial insulating layer and from the first partial insulating layer to the second partial insulating layer, the lateral surface being formed as part of the stepped structure (16 and 17, fig. 14); and

an electrical connecting lead (20 and 21, fig. 2) for electrically contacting the contact surface of the component, the electrical connecting lead comprising a metallization layer (20 and 21, fig. 2) located on the lateral surface, such that the metallization layer meets the contact surface (13 and 14, fig. 2) at an angle less than 90 degrees.

In re Claim 29: (New) The system as claimed in claim 27, wherein the metallization layer (20 and 21, fig. 2) has a layer thickness within a range of from 0.5 μm to 30 μm (1 μm ; col. 5, lns. 67-68).

In re Claim 34: (New) The system as claimed in claim 27, wherein the insulating (2, figs. 12/14 and 15, figs. 13/14) layer is formed by laminating at least one insulating foil onto the component (15, fig. 13).

In re Claim 35: (New) The system as claimed in claim 34, wherein the lateral surface of the insulating layer faces (inside surfaces of layer 2/15, fig. 14) the component (the IGFET(11/13/14), fig. 14),

at least one part of the insulating foil (15, fig. 13; col. 5, lns. 57-62) is laminated onto the component (the IGFET(11/13/14), fig. 14) in such a way that the insulating layer has a surface contour facing away from the component, and

a surface contour of the component is shown in the surface contour of the insulating foil that faces away from the component.

In re Claim 38: (New) The system as claimed in claim 37, wherein the metallization layer (20/21, fig. 2) and/or the section is formed of at least one metal

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selected from the group consisting of aluminum, gold, copper, molybdenum, silver, titanium and tungsten (aluminum, col. 5, Ins. 67-68).

In re Claim 39: (New) The system as claimed in claim 36, wherein the component is a semiconductor component (the IGFET(11/13/14), fig. 14).

In re Claim 42: (New) The system as claimed in claim 27, wherein the insulating layer has a plurality of openings arranged in a row or a matrix (openings 16 and 17 are in a row, fig. 1).

In re Claim 46: (New) A method for producing a system comprising:
providing a component (IGFET(11/13/14), fig. 2) with an electrical contact surface (13 and 14, fig. 2);

producing an insulating layer (2, fig. 12/15, fig. 13) on the component, the insulating layer having an opening (16 and 17, fig. 14) to expose and surround a portion of the contact surface (13 and 14, fig. 14) of the component so that the contact surface is freely accessible, the insulating layer having a lateral surface that defines the opening; and

locating a metallization layer (20 and 21, fig. 2) of a connecting lead on the lateral surface of the insulating layer in such a way that the metallization layer meets the contact surface at an angle less than 90 degrees, wherein

the insulating layer is produced by forming at least first (2, figs. 12/14) and second (15, figs. 13/14; layer 15 is an additional layer; See col. 5, Ins. 60-62) partial insulating layers having openings (16 and 17, fig. 14) with different widths such that a stepped structure is formed from the contact surface to the first partial insulating layer

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and from the first partial insulating layer to the second partial insulating layer, the lateral surface being formed as part of the stepped structure (16 and 17, fig. 14).

In re Claim 47: (New) The method as claimed in claim 46, wherein the insulating layer is formed by a process comprising: laminating at least one insulating foil (15, fig. 13) onto the component(IGFET(11/13/14), fig. 13; and producing an opening (16 and 17, fig. 14) in the insulating foil so that the contact surface (13/14, fig. 14) of the component is exposed.

In re Claim 52: (New) The method as claimed in claim 46, wherein the metallization layer and/or the insulating layer is formed by a vapor deposition method (evaporation, col. 2, Ins. 67 - 68).

Claim Rejections - 35 USC § 103

4. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

5. Claims 28 and 43 rejected under 35 U.S.C. 103(a) as being unpatentable over Nicholas as applied to claim 27 above, in view of Seales (US 3945030).

6. **Nicholas**, as indicated above, discloses all the features of the claims **except**: In re Claim 28: The system as claimed in claim 27, wherein the metallization layer is oriented at an angle to the contact surface within a range of from 30° to 80°.

In re Claim 43: (New) The system as claimed in claim 27, wherein the metallization layer is oriented at an angle to the contact surface within a range of from 50° to 70°.

a. However, **Seales discloses:**

In re Claim 28: (New) The system as claimed in claim 27, wherein the metallization layer (96/97.98, fig. 13) is oriented at an angle to the contact surface within a range of from 30° to 80° (col. 1, Ins. 55 – 68) .

In re Claim 43: (New) The system as claimed in claim 27, wherein the metallization layer is oriented at an angle to the contact surface within a range of from 50° to 70° (col. 1, Ins. 55-68).

Therefore, it would have been obvious to one of ordinary skill in the art at the time of the invention to modify the orientation angle of the metallization layer in Nicholas, with metallization layer being oriented at an angle to the contact surface within a range of from 30° to 80° as taught by Seales, because it makes it possible to obtain excellent contact metallization as disclosed in column 2, lines 24-28.

7. Claims 32 and 44-45 are rejected under 35 U.S.C. 103(a) as being unpatentable over Nicholas as applied to claim 27 above.

8. **Nicholas**, as indicated above, discloses all the features of the claims **except:**

In re Claim 32: The system as claimed in claim 27, wherein the insulating layer has a layer thickness within a range of from 20 µm to 500 µm.

In re Claim 44: The system as claimed in claim 27, wherein the metallization layer has a layer thickness within a range of from 2.0 μm to 20 μm .

In re Claim 45: (New) The system as claimed in claim 27, wherein the insulating layer has a layer thickness within a range of from 50 μm up to an including 200 μm .

a. However, it would have been obvious to one of ordinary skill in the art at the time the invention to modify the thickness of the insulating and metallization layer in Nicholas, with the insulating layer having a thickness within a range of from 20 μm to 500 μm (In re Claim 32) or 50 μm up to an including 200 μm (In re Claim 45) and the metallization layer having a thickness within a range of from 2.0 μm to 20 μm (In re Claim 44) as claimed, because the thicker insulator will reduce hot carrier which increase reliability of the device and thicker metal layer will last longer under electrical and thermal stresses to make the device more durable, since it has been held that where the general conditions of a claim are disclosed in prior art, discovering the optimum or working ranges involves only routine skill in the art. In re Aller, 105 USPQ 233.

9. Claims 36, 37, 53, 54 and 55 rejected under 35 U.S.C. 103(a) as being unpatentable over Nicholas as applied to claim 27 and 46 above, in view of Liu et al. (US 4988412).

10. **Nicholas**, as indicated above, discloses all the features of the claims **except:** In re Claim 36: The system as claimed in claim 27, wherein the connecting lead has a section formed of a material different from the metallization layer, which section is

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located on the insulating layer and is provided with a thickness greater than that of the metallization layer.

In re Claim 37: (New) The system as claimed in claim 36, wherein the section of the connecting lead is electrodeposited.

In re Claim 53: (New) The method as claimed in claim 46, wherein a section of the connecting lead is formed separately from the metallization layer, the section being produced on the insulating layer to have a thickness which exceeds that of the metallization layer.

In re Claim 54: (New) The method as claimed in Claim 53, wherein a metal is electrodeposited to produce the section on the insulating layer.

In re Claim 55: (New) The method as claimed in claim 53, wherein, while the section (60, fig. 4D) is being produced, the opening in the insulating layer is closed.

b. However, **Liu discloses:**

In re Claim 36: (New) The system as claimed in claim 27, wherein the connecting lead has a section (60, fig. 4D) formed of a material different from the metallization layer (30/40, fig. 4D), which section is located on the insulating layer and is provided with a thickness greater than that of the metallization layer.

In re Claim 37: (New) The system as claimed in claim 36, wherein the section of the connecting lead is electrodeposited (col. 8, Ins. 20-33).

In re Claim 53: (New) The method as claimed in claim 46, wherein a section (60, fig. 4D) of the connecting lead is formed separately from the metallization layer (30/40,

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fig. 4D), the section being produced on the insulating layer to have a thickness which exceeds that of the metallization layer.

In re Claim 54: (New) The method as claimed in Claim 53, wherein a metal is electrodeposited to produce the section on the insulating layer (col. 8, Ins. 20-33).

In re Claim 55: (New) The method as claimed in claim 53, wherein, while the section (60, fig. 4D) is being produced, the opening in the insulating layer (26, fig. 4D) is closed.

Therefore, it would have been obvious to one of ordinary skill in the art at the time of the invention to modify the connecting lead in Nicholas, with a section of the connecting lead is formed separately from the metallization layer, the section being produced on the insulating layer to have a thickness which exceeds that of the metallization layer (In re claims 36, 53 and 55) and wherein the section of the connecting lead is electrodeposited (In re claims 37 and 54) by Liu, because this will provide for fine pattern resolution and selective deposition of metal which will increase precision of metal pattern as disclosed in column 5, lines 9-18.

11. Claims 40 and 41 rejected under 35 U.S.C. 103(a) as being unpatentable over Nicholas as applied to claim 39 above, in view of Admitted Prior Art (APA).

12. Nicholas, as indicated above, discloses all the features of the claims **except:**

In re Claim 40: (New) The system as claimed in claim 39, wherein the semiconductor component is a power semiconductor component.

In re Claim 41: (New) The system as claimed in claim 40, wherein the power semiconductor component is a component selected from the group consisting of a diode, a MOSFET, a IGBT, a thyristor and a bipolar transistor.

c. **However, APA discloses:**

In re Claim 40: (New) The system as claimed in claim 39, wherein the semiconductor component is a power semiconductor component ([0003]).

In re Claim 41: (New) The system as claimed in claim 40, wherein the power semiconductor component is a component selected from the group consisting of a diode, a MOSFET, a IGBT, a thyristor and a bipolar transistor ([0003]).

Therefore, it would have been obvious to one of ordinary skill in the art at the time of the invention to modify the integrated circuit(IC) in Nicholas, with the power semiconductor component as taught by APA, because Nicholas is silent to what kind of IC is being formed.

13. Claims 48 and 49 are rejected under 35 U.S.C. 103(a) as being unpatentable over Nicholas as applied to claim 46 above, in view of Neugenbauer et al. (US 5291066).

14. **Nicholas**, as indicated above, discloses all the features of the claims **except:**

In re Claim 48: The method as claimed in claim 47, wherein the insulating foil is laminated under a partial vacuum.

In re Claim 49: The method as claimed in claim 47, wherein the opening in the insulating foil is made by laser ablation.

d. **However, Neugenbauer discloses:**

In re Claim 48: The method as claimed in claim 47, wherein the insulating foil (18/20, figs. 1a and 3b) is laminated under a partial vacuum (cvd, ALE, col. 7, Ins. 5 - 22).

In re Claim 49: The method as claimed in claim 47, wherein the opening (25, figs. 1a and 3a) in the insulating foil is made by laser ablation (col. 8, Ins. 31- 51).

Therefore, it would have been obvious to one of ordinary skill in the art at the time of the invention to modify how the insulating foil is laminated and how the opening in the insulating foil is made in Nicholas, with the insulating foil being laminated under a partial vacuum (In re Claim 48) and forming the opening in the insulating foil by laser ablation (In re Claim 49) taught by Neugenbauer, because Nicholas is silent to particulars of how the insulating foil is laminated and how the opening in the insulating foil is made.

15. Claims 50 and 51 are rejected under 35 U.S.C. 103(a) as being unpatentable over Nicholas as applied to claim 46 above, in view of Kao et al. (US 6338361).

16. **Nicholas**, as indicated above, discloses all the features of the claims **except:**

In re Claim 50: The method as claimed in claim 46, wherein in order to produce the insulating layer on the component, a compressed air process is used wherein paint is applied to the component.

In re Claim 51: The method as claimed in claim 50, wherein the paint is a photo-sensitive paint.

e. However, Kao discloses:

In re Claim 50: (New) The method as claimed in claim 46, wherein in order to produce the insulating layer (photoresist) on the component, a compressed air process is used wherein paint is applied to the component (col. 3, Ins. 27-45).

In re Claim 51: (New) The method as claimed in claim 50, wherein the paint is a photo-sensitive paint (photoresist; col. 3, Ins. 27 - 45).

Therefore, it would have been obvious to one of ordinary skill in the art at the time of the invention to modify the insulating layer and how it is formed in Nicholas, with the photoresist paint method as taught by Kao, because using a photoresist as the insulating layer reduces steps, via a separate masking step is not need to form the opening in the insulating layer, which reduces cost of making the device.

Response to Arguments

2. Applicant's arguments with respect to claims 27-29, 32 and 34-55, received 11/30/09, have been considered but are moot in view of the new ground(s) of rejection.

Conclusion

3. Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to RON POMPEY whose telephone number is (571)272-1680. The examiner can normally be reached on 9AM - 5PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Charles Garber can be reached on (571) 272-2194. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

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/Walter L. Lindsay, Jr./
Primary Examiner, Art Unit 2812

/Ron Pompey/
Examiner, Art Unit 2812
02/26/10